Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
S1	5	(("6204524") or ("6300662") or ("6741283") or ("6744084") or ("6262703")).PN.	USPAT	OR	OFF	2005/11/04 12:06
S3	1	("6369853").PN.	USPAT	OR	OFF	2005/11/02 13:58
S7	2040	((257/291-292) or (438/48)).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/11/04 16:02
S9	328	rhodes.in. and micron.as.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/11/02 14:07
S10	119	S9 and @pd<="20011126"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/11/02 14:57
S11	1	("6639261").PN.	USPAT	OR	OFF	2005/11/02 14:58
S12	3	(("6204524") or ("6310366") or ("6326652")).PN.	USPAT	OR	OFF	2005/11/02 18:50
S14	4	(("6150683") or ("5965875") or ("5898209") or ("5841159")).PN.	USPAT	OR	OFF	2005/11/02 18:53
S15	3	(("6429470") or ("6204524") or ("5461425")).PN.	USPAT	OR	OFF	2005/11/02 20:00
S16	1	("6940552").PN.	USPAT	OR	OFF	2005/11/03 15:18
S24	12495	(semiconductor adj energy).as. and @ad<="20021126"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/11/04 16:01
S25	704	S24 and (cmos and capacitor and gate)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/11/03 18:39
S35	15315	(semiconductor adj energy).as.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/11/04 16:02

S36	291878	(sony).as.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/11/04 16:02
S37	61214	(kodak).as.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/11/04 16:02
S38	2041	((257/291-292) or (438/48)).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/11/04 16:02
S39	276533	(S35 S36 S37 S38) and @pd<="20011126"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/11/04 16:03
S40	144	S39 and (cmos$1imag$3 or (cmos near3 imag$3))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/11/04 18:17
S44	4888	(cmos$1imag$3 or (cmos near3 imag$3)) and @ad<="20021126"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/11/04 21:33
S45	1060	S44 and capacitor	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/11/04 18:20
S46	144	S45 and (capacitor near6 connect$3 near6 gate)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/11/04 18:35

S47	2	("6023081").PN.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/11/04 18:35
S48	4888	(cmos$1imag$3 or (cmos near3 imag$3)) and @ad<="20021126"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/11/07 12:39
S49	1060	S48 and capacitor	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/11/04 21:33
S53	6	S49 and (global$1shutter$3 or (global adj shutter$3))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/11/04 21:46
S54	380	S49 and (source$1follow$3 or (source adj follow$3))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/11/04 22:48
S55	317	S49 and (row$1select$3 or (row adj select$3))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/11/04 21:47
S56	3	S49 and ((row$1select$3 or (row adj select$3)) near6 connect$4 near6 capacitor)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/11/04 22:35
S57	115	S49 and ((row$1select$3 or (row adj select$3)) near3 (transitor or gate))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/11/04 22:33

S59	136	S48 and (gate near6 connect$4 near6 capacitor)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/11/04 22:35
S60	78	S49 and ((source$1follow$3 or (source adj follow$3)) near8 connect$3 near8 capacitor)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/11/04 22:54
S61	8	S49 and (capacitor near8 (field$1oxide or (field adj oxide)))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/11/07 12:34
S63	22	S49 and (capacitor near8 isolation)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/11/04 22:57
S64	200	capacitor near10 connect$4 near10 (gate or transistor) near10 advantage	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/11/04 23:21
S65	0	S48 and S64	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/11/04 23:21
S66	235	capacitor near10 connect$4 near10 (gate or transistor) and S48	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/11/04 23:22
S67	196	S66 not (rhodes and @pd>="20021126")	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/11/04 23:22

S68	2183	(cmos$1pixel$1 or (cmos near3 pixel)) and @ad<="20021126"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/11/07 12:33
S69	6	S68 and (capacitor near10 (field$1oxide or (field adj oxide)))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/11/07 12:40
S70	51	S68 and (capacitor near10 isolat$6)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/11/07 12:36
S71	4888	(cmos$1imag$3 or (cmos near3 imag$3)) and @ad<="20021126"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/11/07 12:39
S72	1719	(cmos$1detect$3 or (cmos near3 detect$3)) and @ad<="20021126"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/11/07 12:40
S73	7102	S68 S71 S72	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/11/07 12:40
S74	8	S73 and (capacitor near10 (field$1oxide or (field adj oxide)))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/11/07 12:53
S75	21	S73 and (capacitor same (field$1oxide or (field adj oxide)))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/11/07 13:03

S76	226	S73 and (capacitor same oxide)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/11/07 13:22
S77	276	S73 and (capacitor near10 connect$4 near10 gate)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/11/07 13:36
S78	1	S73 and (capacitor near10 (global$1shutter$1 or (global adj shutter)))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/11/07 13:46
S79	93	S73 and (capacitor near10 (row$1select$1 or (row adj select)))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/11/07 13:37
S80	13	S73 and (global$1shutter$1 or (global adj shutter))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/11/07 13:47